

Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter		FQD4P25 / FQU4P25	Units
V _{DSS}	Drain-Source Voltage		-250	V
I _D	Drain Current - Continuous (T _C = 25	°C)	-3.1	А
	- Continuous (T _C = 100°C)		-1.96	А
I _{DM}	Drain Current - Pulsed	(Note 1)	-12.4	А
V _{GSS}	Gate-Source Voltage		± 30	V
E _{AS}	Single Pulsed Avalanche Energy	(Note 2)	280	mJ
I _{AR}	Avalanche Current	(Note 1)	-3.1	А
E _{AR}	Repetitive Avalanche Energy	(Note 1)	4.5	mJ
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	-5.5	V/ns
PD	Power Dissipation ($T_A = 25^{\circ}C$) *		2.5	W
	Power Dissipation ($T_C = 25^{\circ}C$)		45	W
	- Derate above 25°C	-	0.36	W/°C
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +150	°C
Τ _L	Maximum lead temperature for soldering purposes, 1/8" from case for 5 seconds		300	°C

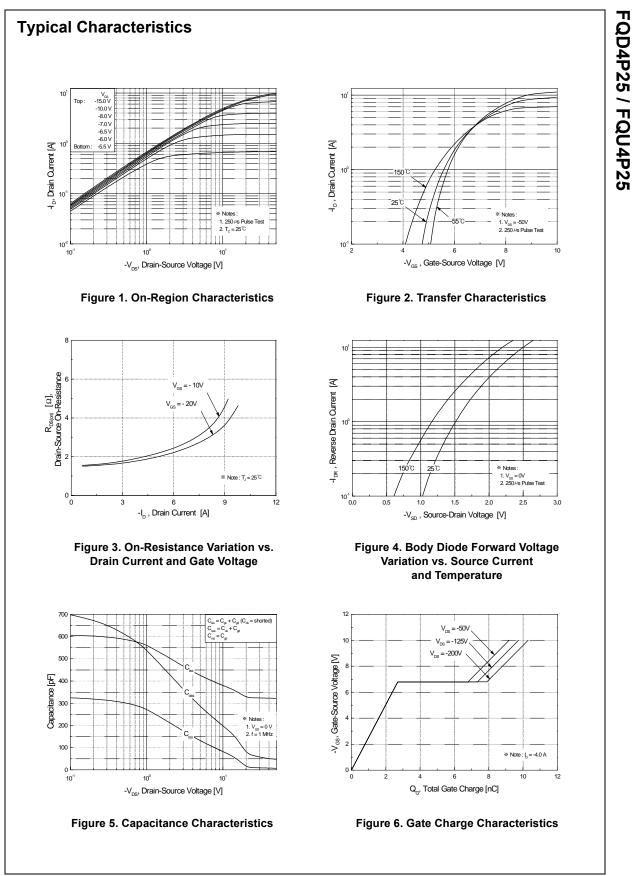
Thermal Characteristics

Symbol	Parameter	Тур	Max	Units
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case		2.78	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient *		50	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient		110	°C/W

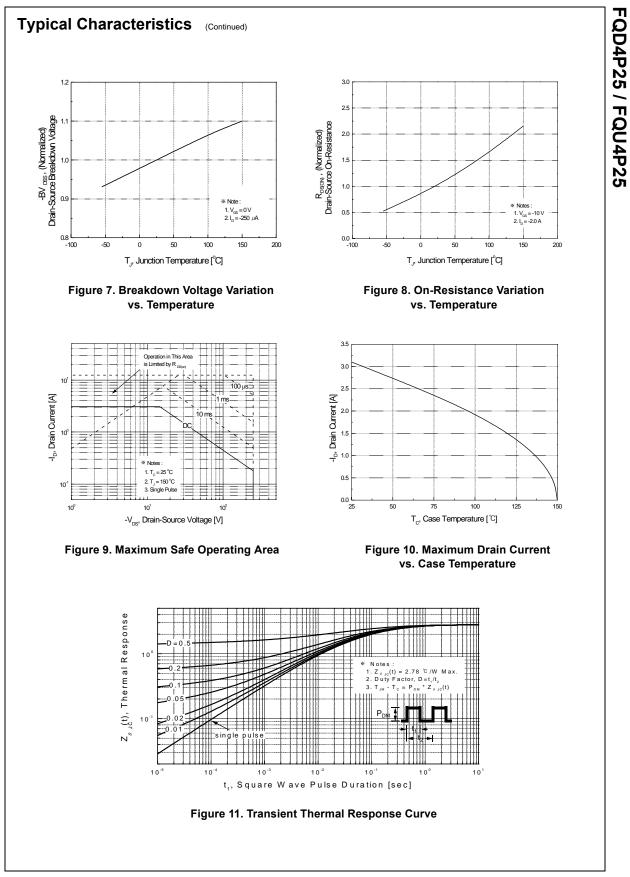
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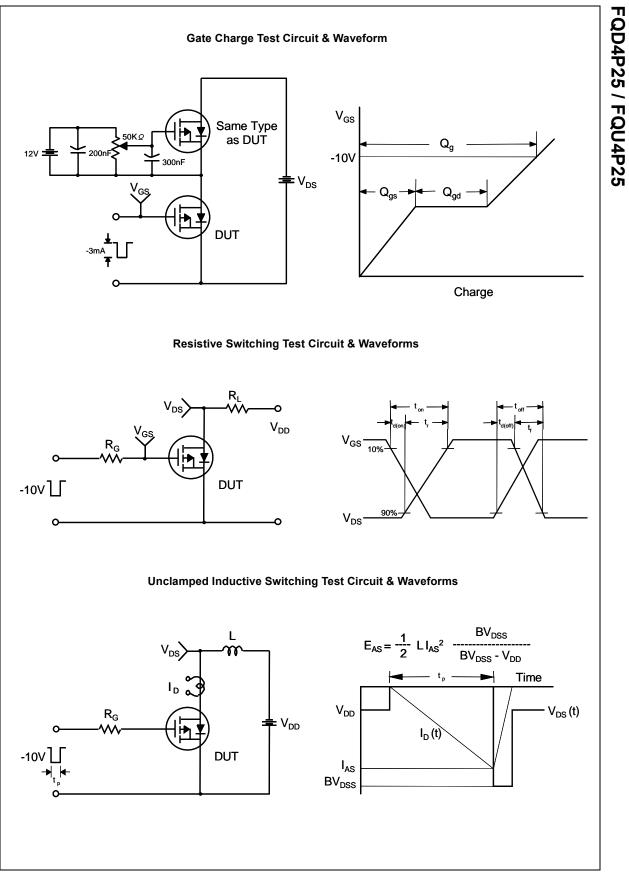
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Cha	racteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0 V, I _D = -250 μA	-250			V
∆BV _{DSS} ∆T _J	Breakdown Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$, Referenced to 25°C		-0.21		V/°C
I _{DSS}		$V_{DS} = -250 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			-1	μA
	Zero Gate Voltage Drain Current	$V_{DS} = -200 \text{ V}, \text{ T}_{C} = 125^{\circ}\text{C}$			-10	μA
GSSF	Gate-Body Leakage Current, Forward	$V_{GS} = -30 \text{ V}, V_{DS} = 0 \text{ V}$			-100	nA
GSSR	Gate-Body Leakage Current, Reverse	$V_{GS} = 30 \text{ V}, V_{DS} = 0 \text{ V}$			100	nA
On Cha	racteristics					
/ _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	-3.0		-5.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	$V_{GS} = -10 \text{ V}, I_D = -1.55 \text{ A}$		1.63	2.1	Ω
ĴFS	Forward Transconductance	$V_{DS} = -40 \text{ V}, \text{ I}_{D} = -1.55 \text{ A}$ (Note 4)		2.0		S
Dynam	c Characteristics					
Siss	Input Capacitance	V _{DS} = -25 V, V _{GS} = 0 V,		325	420	pF
Soss	Output Capacitance	f = 1.0 MHz		65	85	pF
2 _{rss}	Reverse Transfer Capacitance			10	13	pF
Switchi	ng Characteristics					
d(on)	Turn-On Delay Time	V _{DD} = -125 V, I _D = -4.0 A,		9.5	30	ns
r	Turn-On Rise Time	$R_G = 25 \Omega$		60	130	ns
d(off)	Turn-Off Delay Time			14	40	ns
f	Turn-Off Fall Time	(Note 4, 5)		27	65	ns
ζ ^g	Total Gate Charge	$V_{DS} = -200 \text{ V}, \text{ I}_{D} = -4.0 \text{ A},$		10.3	14	nC
ג gs	Gate-Source Charge	V _{GS} = -10 V		2.7		nC
ጋ _{gd}	Gate-Drain Charge	(Note 4, 5)		5.2		nC
Drain-S	ource Diode Characteristics a	nd Maximum Ratings				
S	Maximum Continuous Drain-Source Did				-3.1	А
SM	Maximum Pulsed Drain-Source Diode F	Forward Current			-12.4	А
/ _{SD}	Drain-Source Diode Forward Voltage	V _{GS} = 0 V, I _S = -3.1 A			-5.0	V
rr	Reverse Recovery Time	$V_{GS} = 0 V, I_{S} = -4.0 A,$		140		ns
ე ^{rr}	Reverse Recovery Charge	$dI_{F} / dt = 100 \text{ A}/\mu \text{s} $ (Note 4)		0.64		μC
L = 46.6mH, I _{SD} ≤ -4.0A, Pulse Test :	ating : Pulse width limited by maximum junction tempe $I_{AS} = -3.1A$, $V_{DD} = -50V$, $R_G = 25 \Omega$, Starting $T_J = 25^{\circ}$ di/dt $\leq 300A/\mu_S$, $V_{DD} \leq SV_{DSS}$, Starting $T_J = 25^{\circ}C$ Pulse width $\leq 300\mu_S$. Duty cycle $\leq 2\%$ independent of operating temperature					

FQD4P25 / FQU4P25

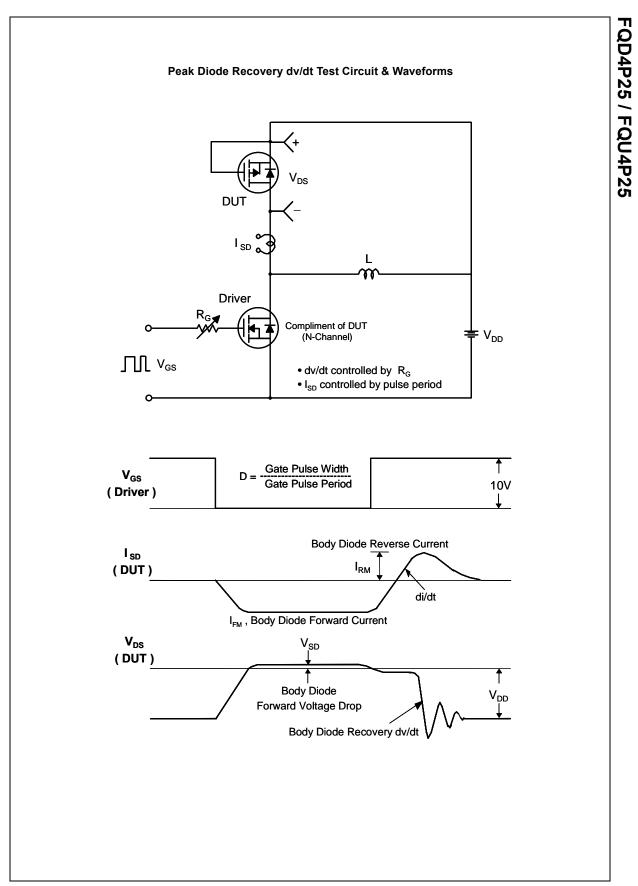


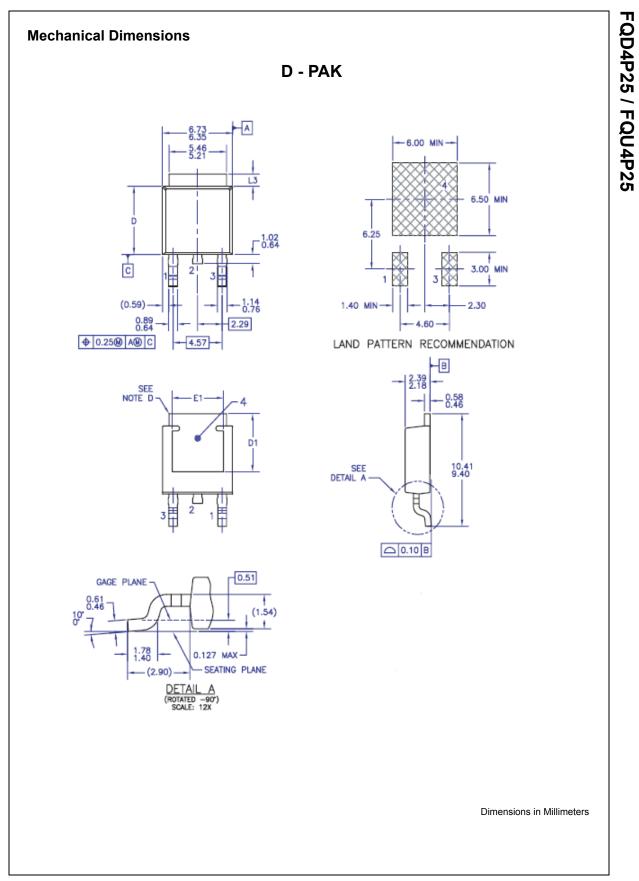
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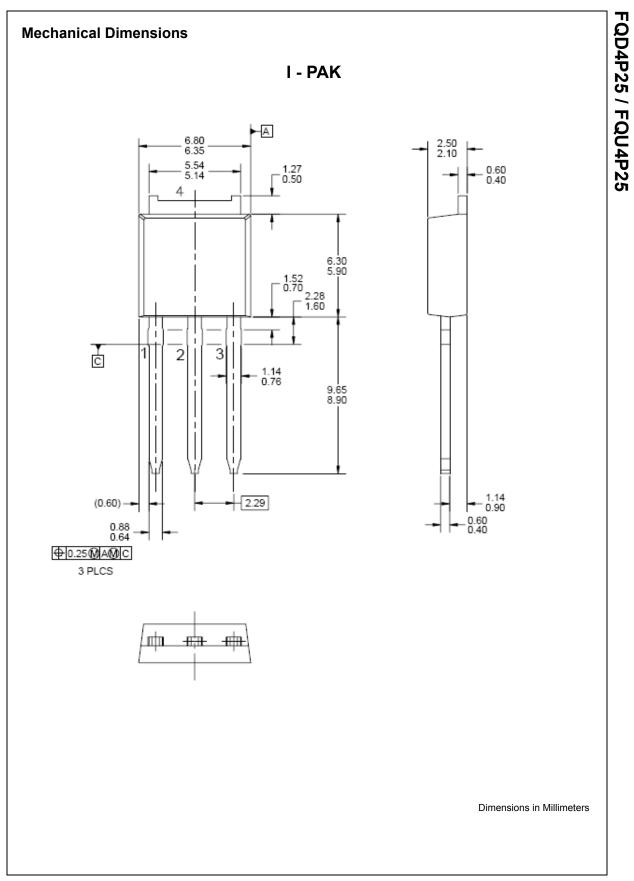




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